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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	CONDITIONS	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		$V_R$	3.0	V			
DC forward current		I <sub>F</sub>	25	mA			
Surge forward current	$t_P \le 1.0 \ \mu s, 300 \ pulses/s$	I <sub>FSM</sub>	1.0	Α			
Power dissipation		P <sub>diss</sub>	45	mW			
OUTPUT							
Supply voltage		Vs	-0.5 to +30	V			
Output voltage		V <sub>O</sub>	-0.5 to +20	V			
Output current		Ιο	8	mA			
Power dissipation		P <sub>diss</sub>	100	mW			
COUPLER							
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C			
Ambient temperature range		T <sub>amb</sub>	-55 to +100	°C			
Junction temperature		Tj	100	°C			
Soldering temperature	Max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C			

#### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

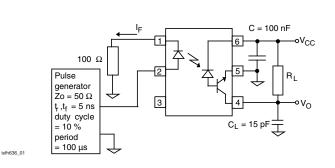
DADAMETED	TEST CONDITION	SYMBOL	RAINI	TVD	BAAV	LINIT
PARAMETER	TEST CONDITION	STMBUL	MIN.	TYP.	MAX.	UNIT
input						
Forward voltage	I <sub>F</sub> = 16 mA	$V_{F}$	-	1.5	1.8	V
Reverse current	V <sub>R</sub> = 3 V	I <sub>R</sub>	-	0.5	10	μΑ
Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz	Co	-	125	-	pF
Thermal resistance		R <sub>thja</sub>	-	700	-	K/W
output	·					
Logic high supply current	I <sub>F</sub> = 0 V, V <sub>O</sub> (open), V <sub>CC</sub> = 15 V, T <sub>amb</sub> = 25 °C	I <sub>CCH</sub>	-	0.01	1	μА
	$I_F = 0 \text{ V}, V_O \text{ (open)}, V_{CC} = 15 \text{ V}$	I <sub>CCH</sub>	-	0.01	2	μΑ
Output current, output high	$I_F = 0 \text{ V}, V_O \text{ (open)}, V_{CC} = 5.5 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$	I <sub>OH</sub>	-	0.003	0.5	μΑ
	I <sub>F</sub> = 0 V, V <sub>O</sub> (open), V <sub>CC</sub> =15 V, T <sub>amb</sub> = 25 °C	Іон	-	0.01	1	μΑ
	I <sub>F</sub> = 0 V, V <sub>O</sub> (open), V <sub>CC</sub> =15 V	I <sub>OH</sub>	-		50	μΑ
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz	C <sub>CE</sub>	-	3	-	pF
Thermal resistance		R <sub>thja</sub>	-	300	-	K/W
coupler	·					
Coupling capacitance		C <sub>C</sub>	-	0.6	-	pF
Collector emitter saturation voltage	I <sub>F</sub> = 16 mA, I <sub>O</sub> = 2.4 mA, V <sub>CC</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	V <sub>OL</sub>	-	0.1	0.4	V
Supply current, logic low	$I_F = 16 \text{ mA}, V_O \text{ open}, V_{CC} = 15 \text{ V}$	I <sub>DD</sub>	-	80	-	

### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



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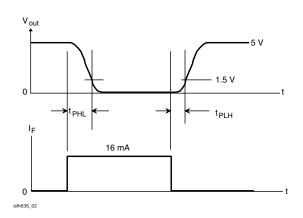
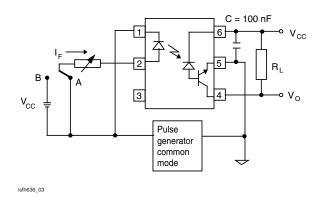


Fig. 1 - Test Setup

Fig. 2 - Switching Time Measurement

<b>CURRENT TRANSFER RATIO</b> ( $T_{amb} = 0$ °C to 70 °C unless otherwise specified, typ. values $T_{amb} = 25$ °C)						
PARAMETER	TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT					UNIT
I <sub>C</sub> /I <sub>F</sub>	$I_F = 16 \text{ mA}, V_O = 0.4 \text{ V}, V_{CC} = 4.5 \text{ V},$ $T_{amb} = 25 \text{ °C}$	CTR	19	30	-	%
	$I_F = 16 \text{ mA}, V_O = 0.5 \text{ V}, V_{CC} = 4.5 \text{ V}$	CTR	15	ı	-	%

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C unless otherwise specified)						
PARAMETER	ER TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT					
Propagation delay time (high to low)	$I_F = 16 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 1.9 \text{ k}\Omega$	t <sub>PHL</sub>	-	0.3	0.8	μs
Propagation delay time (low to low)	$I_F = 16 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 1.9 \text{ k}\Omega$	t <sub>PLH</sub>	-	0.3	0.8	μs





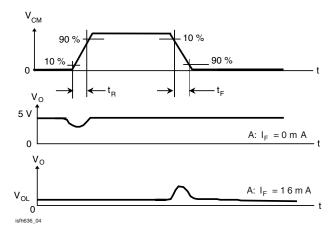


Fig. 4 - Measurement Waveform of CMR

<b>COMMON MODE TRANSIENT IMMUNITY</b> (T <sub>amb</sub> = 25 °C unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode transient immunity (high)	$I_{O} = 0$ mA, $V_{CM} = 1500 V_{P-P}$ , $R_{L} = 1.9 k\Omega$ , $V_{CC} = 5.0 V$	CM <sub>H</sub>	-	10 000	-	V/µs
Common mode transient immunity (low)	$I_{O}$ = 16 mA, $V_{CM}$ = 1500 $V_{P-P}$ , $R_{L}$ = 1.9 k $\Omega$ , $V_{CC}$ = 5.0 V	CM <sub>L</sub>	-	10 000	-	V/µs

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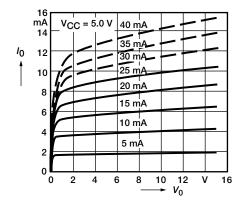


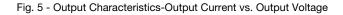
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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55/100/21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	8000	V <sub>peak</sub>
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V <sub>IORM</sub>	890	V <sub>peak</sub>
Isolation resistance	T <sub>amb</sub> = 25 °C, V <sub>IO</sub> = 500 V	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
	T <sub>amb</sub> = 100 °C, V <sub>IO</sub> = 500 V	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Output safety power		Pso	700	mW
Input safety current		I <sub>SI</sub>	400	mA
Input safety temperature		T <sub>S</sub>	175	°C
Creepage distance	DIP-6		≥ 7	mm
Clearance distance	DIP-6		≥ 7	mm
Creepage distance	DIP-6, option 6		≥8	mm
Clearance distance	DIP-6, option 6		≥ 8	mm
Creepage distance	SMD-6, option 7		≥ 7	mm
Clearance distance	SMD-6, option 7		≥ 7	mm
Creepage distance	SMD-6, option 9		≥7	mm
Clearance distance	SMD-6, option 9		≥7	mm
Insulation thickness		DTI	≥ 0.4	mm

#### Note

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)





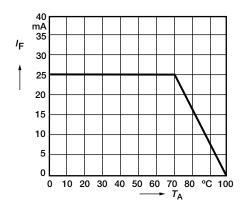


Fig. 6 - Permissible Forward Current of Emitting Diode vs.
Ambient Temperature

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.



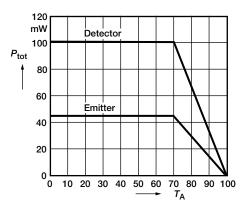


Fig. 7 - Permissible Total Power Dissipation vs. Ambient Temperature

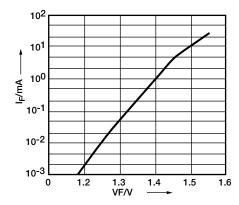


Fig. 8 - Forward Current of Emitting Diode vs. Forward Voltage

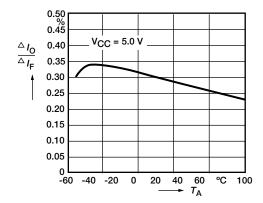


Fig. 9 - Small Signal Transfer Ratio vs. Forward Current

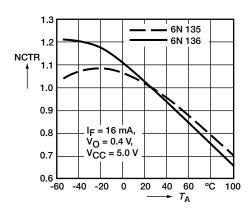


Fig. 10 - Current Transfer Ratio (Normalized) vs.
Ambient Temperature

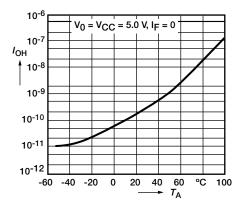


Fig. 11 - Output Current (High) vs. Ambient Temperature

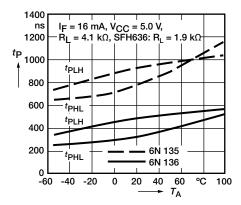


Fig. 12 - Delay Times vs. Ambient Temperature





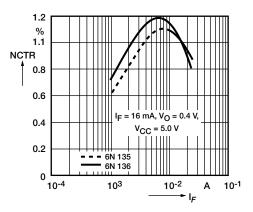
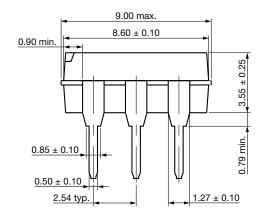
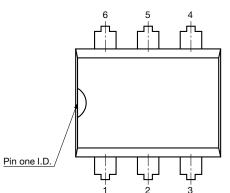


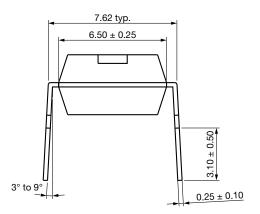
Fig. 13 - Current Transfer Ratio (Normalized) vs. Forward Current

### PACKAGE DIMENSIONS in inches (millimeters)

### DIP-6





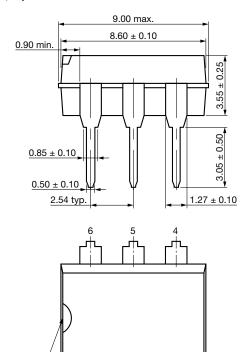


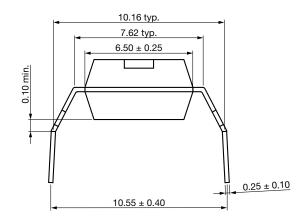


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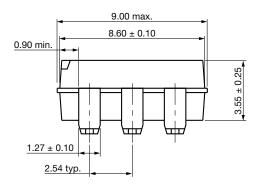
### DIP-6, Option 6

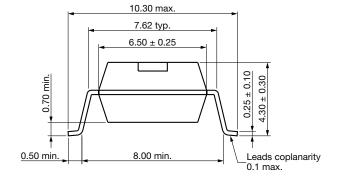


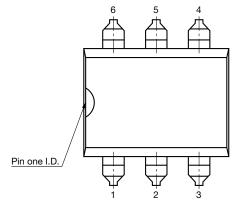


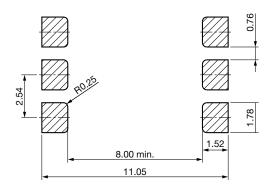
### SMD-6, Option 7

Pin one I.D.





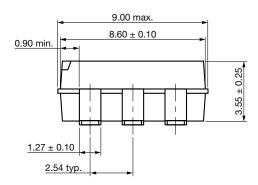


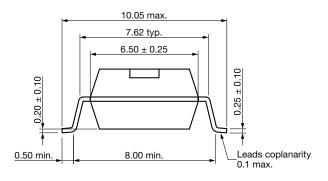


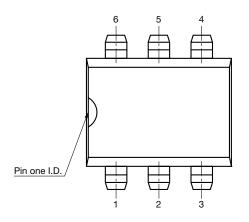
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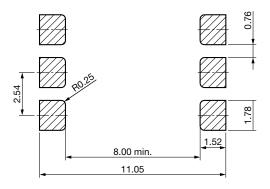
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### SMD-6, Option 9









#### **SOLDER PROFILES**

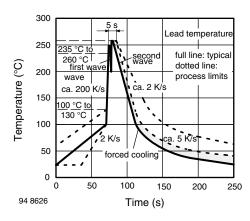


Fig. 14 - Wave Soldering Double Wave Profile According to J.STD-020 for DIP Devices

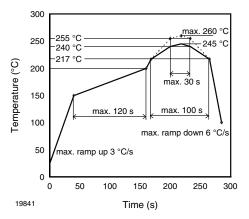


Fig. 15 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020

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